## NOTE

# Variation of Mean Si-O Bond Lengths in Silicon-Oxygen Octahedra 

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#### Abstract

The mean bond length $\mathrm{Si}-\mathrm{O}$ in silicon-oxygen octahedra is a function of the mean coordination number of the oxygen atoms $(C N)$ in the octahedron: $(\mathrm{Si}-\mathrm{O})_{\text {mcan }}=1.729+0.013 C N$. The radius of Si in six coordination against oxygen is 0.407 A .


Recently Reid et al. (1) have reported on the synthesis of high-pressure pyrochlore-type $\mathrm{Sc}_{2}^{[8]} \mathrm{Si}_{2}^{[6]} \mathrm{O}_{7}^{[4]}$ and $\mathrm{In}_{2}^{[8]} \mathrm{Si}_{2}^{[6]} \mathrm{O}_{7}^{[4]}$ (the superscripts refer to the coordination numbers of the atoms). This adds two more compounds to the short list of substances containing sixcoordinated silicon. Since octahedrally coordinated silicon must occur in the lower mantle of the earth the dimensions of the $\mathrm{SiO}_{6}$ group are of interest for the discussion of the crystal chemistry of mantle minerals. Therefore Reid et al. tabulated these dimensions for those structures containing $\mathrm{Si}^{[6]}$ and known to them. Their Table V contains data on seven crystallographically independent $\mathrm{SiO}_{6}$ octahedra in seven different compounds. The weighted mean of the $\mathrm{Si}-\mathrm{O}$ distance is reported by them to be $1.782(14) \AA$.

However, the number of crystallographically independent $\mathrm{SiO}_{6}$ octahedra can be almost doubled by including the six $\mathrm{SiO}_{6}$ octahedra observed in the cubic polymorph of $\mathrm{SiP}_{2} \mathrm{O}_{7}$ (2). The weighted mean of the average $\mathrm{Si}-\mathrm{O}$ distances in the 13 octahedra is then $1.771 \AA$ (Table I). In going from the smaller to the larger data sample the range of the values increases from $0.04 \AA(1.761$ to $1.800 \AA$ ) to $0.07 \AA(1.730$ to $1.800 \AA)$. This larger scatter
is due most likely to the dependence of the octahedral $\mathrm{Si}-\mathrm{O}$ distance on the coordination number of the oxygen atoms. In Table I the mean coordination numbers of the oxygen atoms in a given octahedron are listed together with calculated $\mathrm{Si}-\mathrm{O}$ values obtained from the equation

$$
\begin{equation*}
(\mathrm{Si}-\mathrm{O})_{\text {mean }}=1.729+0.013 C N \tag{1}
\end{equation*}
$$

which is based on regression calculations involving the 13 observed $\mathrm{Si}-\mathrm{O}$ distances. The magnitude of the slope of this equation is very close to the value of the slope ( 0.012 ) which can be obtained from the radii of oxygen with different coordination numbers listed by Shannon and Prewitt (8). The calculated values agree reasonably well with the observed values (considering the standard deviations of the observations) in all cases save one. The mean $\mathrm{Si}-\mathrm{O}$ bond length in tris( $o$-phenylenedioxy)siliconate is observed as $0.025 \AA$ longer than it is calculated and it is also the most precisely determined of the values in Table I. The length of this $\mathrm{Si}-\mathrm{O}$ bond might be due to the fact that the oxygen atoms are not only bonding to Si but also forming strong, covalent, partial double bonds with carbon (mean length of C-O $1.357 \AA$ ).

TABLE I
Observed and Calculated Mean Distances Si ${ }^{[6]}$-O

| Substance | $(\mathrm{Si}-\mathrm{O})_{\mathrm{obs}}$ <br> ( $\AA$ ) | $C N$ of $\mathrm{O}^{a}$ | $(\mathrm{Si}-\mathrm{O})_{\text {calc }}$ <br> ( $\AA$ | $\Delta^{b}(\AA)$ | Reference |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Cubic $\mathrm{SiP}_{2} \mathrm{O}_{7}$ | 1.750(12) ${ }^{\text {c }}$ | 2 | 1.755 | -0.005 | (2) |
| Cubic $\mathrm{SiP}_{2} \mathrm{O}_{7}$ | 1.750(12) | 2 | 1.755 | -0.005 | (2) |
| Cubic $\mathrm{SiP}_{2} \mathrm{O}_{7}$ | $1.755(12)$ | 2 | 1.755 | 0 | (2) |
| Cubic $\mathrm{SiP}_{2} \mathrm{O}_{7}$ | 1.758(12) | 2 | 1.755 | 0.003 | (2) |
| Cubic $\mathrm{SiP}_{2} \mathrm{O}_{7}$ | 1.755(12) | 2 | 1.755 | 0 | (2) |
| Cubic $\mathrm{SiP}_{2} \mathrm{O}_{7}$ | $1.730(11)$ | 2 | 1.755 | -0.025 | (2) |
| $\mathrm{SiP}_{2} \mathrm{O}_{7}$ AIII | $1.763(7)$ | 2 | 1.755 | 0.008 | (3) |
| $\mathrm{SiP}_{2} \mathrm{O}_{7}$ AIV | 1.798(31) | 2 | 1.755 | 0.043 | (4) |
| $\left(\mathrm{C}_{5} \mathrm{H}_{5} \mathrm{NH}\right)_{2}\left[\left(\mathrm{C}_{6} \mathrm{H}_{4} \mathrm{O}_{2}\right)_{3} \mathrm{Si}\right]$ | 1.784(3) | 2.33 | 1.759 | 0.025 | (5) |
| Stishovite | $1.775(7)$ | 3 | 1.768 | 0.007 | (6) |
| $\mathrm{Sc}_{2} \mathrm{Si}_{2} \mathrm{O}_{7}$ | 1.761(7) | 4 | 1.781 | -0.020 | (1) |
| $\mathrm{In}_{2} \mathrm{Si}_{2} \mathrm{O}_{7}$ | $1.800(5)$ | 4 | 1.781 | 0.019 | (1) |
| Thaumasite | 1.783(7) | 4 | 1.781 | 0.002 | (7) |
| Weighted grand mean | 1.771(13) |  |  |  |  |

${ }^{a}$ Mean coordination number of all oxygen atoms in $\mathrm{SiO}_{6}$ octahedron.
${ }^{b}$ Difference $(\mathrm{Si}-\mathrm{O})_{\text {obs }}-(\mathrm{Si}-\mathrm{O})_{\text {calc. }}$.
${ }^{c}$ Standard deviations calculated by taking the square root of the sum of the variances of the individual bond lengths divided by 5 . They are in units of the least significant digits of the value.

Using Eq. (1) it can be estimated that the $\mathrm{Si}-\mathrm{O}$ bond length in perovskite-type $\mathrm{MgSiO}_{3}$ (9) should be 1.790 (7) $\AA$, since the average coordination number of oxygen in this compound is 4.67 (10). This estimate is identical with the prediction made by Reid et al. (1) based on the bond length vs molar volume relationship for the perovskite type.

Based on Eq. (1) the radius of silicon in six coordination against oxygen is $0.407 \AA$. This is slightly larger than the radius of $0.400 \AA$ reported previously $(8,11)$. The reason for the difference may be due to the fact that the bond lengths used in deriving the earlier radius were taken from $\mathrm{SiF}_{6}$ groups and from $\mathrm{SiO}_{6}$ groups.

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